

Please type a plus sign (+) inside this box. FORM PTO/SB/08

Substitute for form 1449A/PTO				<i>Complete if Known</i>	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Application Number	10/16 U.S.
				Filing Date	10/07/504
				First Named Inventor	Kenneth R. Burch
				Group Art Unit	10
				Examiner Name	
Sheet	1	of	2	Attorney Docket Number	SC11767TC

U. S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

Examiner Signature	M.Wilczewski	Date Considered	9/03
-----------------------	--------------	--------------------	------

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English Language Translation is attached.

Please type a plus sign (+) inside this box. FORM PTO/SB/08

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				<i>Complete if Known</i>	
Sheet		2	of	2	Attorney Docket Number
				SC11767TC	

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ²
<i>MW</i>	AE	Lukas W. Snykman et al., "ME2-6", The 4 th Pacific Rim Conference on Lasers and Electro-Optics, Volume: 1, 2001, pgs. I-108 – I-109.			
<i>MW</i>	AF	Monuko du Plessis et al., "Silicon Light Emitting Devices In Standard CMOS Technology", Semiconductor Conference 2001 IEEE, CAS 2001 Proceedings, International, Volume: 1, 2001, pgs. 231-238.			
<i>MW</i>	AG	L.W. Snyman et al., "An Efficient Low Voltage, High Frequency Silicon CMOS Light Emitting Device and Electro-Optical Interface", 1999 IEEE Electron Device Letters, Vol. 20, No. 12, December, 1999, pgs. 614-617.			
<i>MW</i>	AH	Monuko du Plessis et al., "A Gate-controlled Silicon Light Emitting Diode", Africon 1999 IEEE, Volume 2, 1999, pgs. 1157-1160.			
<i>MW</i>	AI	Lukas W. Snyman et al., "Enhanced Light Emission From A Silicon N+PN CMOS Structure", Southeastcon 1999, Proceedings, IEEE, 1999, pgs. 242-245.			
<i>MW</i>	AJ	Lukas W. Snyman et al., "Practical Si LED's With Standard CMOS Technology", Southeastcon 1998, Proceedings, IEEE, 1998, pgs. 344-347.			
<i>MW</i>	AK	Lukas W. Snyman et al., "Higher-Efficiency Si LED's With Standard CMOS Technology", 1997 Workshop on High Performance Electron Devices for Microwave and Optoelectronic Applications, 1997, EDMO, pgs. 340-345.			

Examiner Signature	<i>M.W. Czajewski</i>	Date Considered	<i>9/03</i>
--------------------	-----------------------	-----------------	-------------

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English Language Translation is attached.